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Vishay Semiconductors

Thyristor High Voltage, Phase Control SCR, 80 A



PRIMARY CHARACTERISTICS				
I _{T(AV)}	80 A			
V _{DRM} /V _{RRM}	1600 V			
V _{TM} (typ.)	1.16 V			
I _{GT}	100 mA			
T _J	-40 °C to +150 °C			
Package	TO-247AD 3L			
Circuit configuration	Single SCR			

FEATURES

- Designed and qualified according to JEDEC®-JESD 47
- 150 °C maximum operating junction temperature
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

Typical usage is in input rectification crowbar (soft start) and AC switch motor control, UPS, welding, and battery charge.

DESCRIPTION

The VS-80TPS16L high voltage series of silicon controlled rectifiers are specifically designed for medium power switching, and phase control applications. The glass passivation technology used, has reliable operation up to 150 °C junction temperature.

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V _{RRM} /V _{DRM}		1600	V	
On-state voltage	V _T	80 A, T _J = 125 °C, typical	1.16	V	
Average rectified forward current	I _{T(AV)}		80		
Maximum continuous RMS on-state current	I _{RMS}		126	Α	
Non-repetitive peak surge current	I _{TSM}		1000		
Maximum rate of rise	dV/dt		1000	V/µs	
Maximum operating junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C	

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	TYP. I _{RRM} /I _{DRM} AT 125 °C mA
VS-80TPS16L-M3	1600	1700	10



PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 113 °C, 180° conduction half sine v	vave	-	80	
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}			-	126	Α
Peak, one-cycle non-repetitive surge current	L	10 ms sine pulse, rated $V_{\mbox{\scriptsize RRM}}$ applied		-	840	
reak, one-cycle non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied	Initial T _J =	-	1000	
I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	T _J maximum	-	3536	A ² s
1-t for fusing	1-1	10 ms sine pulse, no voltage reapplied		-	5000	A ² s
I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	d, T _J = 125 °C	-	50 000	A²√s
		80 A, T _J = 25 °C		1.22	1.40	V
	V _T	160 A, T _J = 25 °C		1.48	1.66	
On-state voltage		80 A, T _J = 125 °C		1.16	1.24	
		160 A, T _J = 125 °C		1.49	1.62	
Low level value of threshold voltage	V _{T01}	T 450 00		-	0.80	V
High level value of threshold voltage	V _{T02}	T _J = 150 °C		-	0.89	v
Low level value of on-state slope resistance	r _{t1}	T 150 °C		-	4.82	0
High level value of on-state slope resistance	r _{t2}	T _J = 150 °C		-	4.51	mΩ
Rate of rise of turned-on current	dl/dt	T_J = 125 °C, V_R = 1000 V, I_T = 100 A, I_{gt} = 450 mA, V_{GT} = 2.5 V		-	500	A/µs
Holding current	I _H	$\frac{I_{H}}{I_{L}}$ Anode supply = 6 V, resistive load, $T_{J} = 25 ^{\circ}\text{C}$		-	200	A
Latching current	ΙL			-	400	mA
Deverse and direct leakage augrent	l/l	T _J = 25 °C		50	200	μΑ
Reverse and direct leakage current	I _{RRM} /I _{DRM}	T _J = 125 °C			60	mA
Rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to 80 % V_{DRM} , I	R _g -k = open	-	1000	V/µs

TRIGGERING						
PARAMETER	SYMBOL		TEST CONDITIONS	TYP.	MAX.	UNITS
Peak gate power	P_{GM}	10 ms sino puls	40		10	W
Average gate power	P _{G(AV)}	To this sine puis	10 ms sine pulse, no voltage reapplied			
Peak gate current	I _{GM}				2.5	Α
Peak negative gate voltage	-V _{GM}			-	10	V
Required DC gate voltage to trigger	V_{GT}	T _J = 25 °C Anode supply = 6 V resistive load		1	1.5	V
Required DC gate to trigger	I _{GT}	T _J = 25 °C Anode supply = 6 V resistive load		-	100	mA
DC gate voltage not to trigger	V_{GD}	T 105 °C V 20 0/ reted value		-	0.20	٧
DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = 80 % rated value			5	mA

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS
Turn-on time	t _{gt}	I_T = 80 A, V_D = 50 % V_{DRM} , I_{gt} = 300 mA, T_J = 25 °C	2	-	
Turn-off time	t _q	I_T = 80 A, V_D = 80 % V_{DRM} , dV/dt = 20 $V/\mu s$, t_p = 200 μs I_{gt} = 100 mA, dI/dt = 10 $A/\mu s$, V_R = 100 V , T_J = 150 °C	150	-	μs



THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	MAX.	UNITS
Maximum operating junction and storage temperature range		T _J , T _{Stg}		-40	150	°C
Maximum thermal resistance, junction to case		R _{thJC}		-	0.23	
Maximum thermal resistance, junction to ambient		R_{thJA}		-	40	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.	20	
Approximate weight				6 (0	.21)	g (oz.)
Mounting torque	minimum			6	(5)	kgf · cm
Mounting torque	maximum			12	(10)	(lbf · in)
Marking device			Case style TO-247AD 3L		80TPS1	6L

△R _{thJ-HS} CONDUCTION PER JUNCTION											
DEVICE	s	SINE HALF-WAVE CONDUCTION				RECTANGULAR WAVE CONDUCTION				UNITS	
DEVICE	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VS-80TPS16L-M3	0.031	0.036	0.040	0.042	0.044	0.028	0.036	0.038	0.040	0.042	°C/W

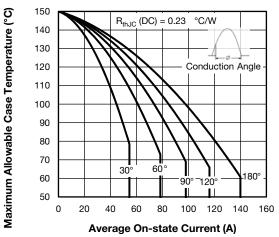


Fig. 1 - Current Rating Characteristics

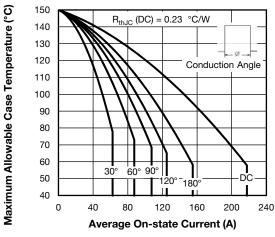


Fig. 2 - Current Rating Characteristics

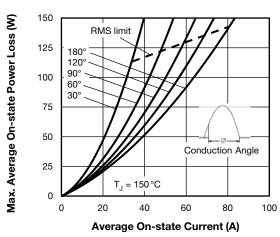


Fig. 3 - On-State Power Loss Characteristics

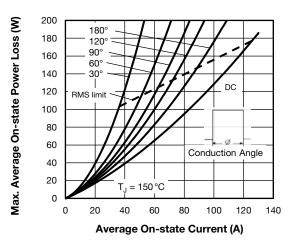


Fig. 4 - On-State Power Loss Characteristics



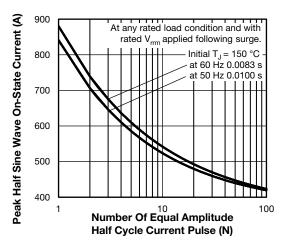


Fig. 5 - Maximum Non-Repetitive Surge Current

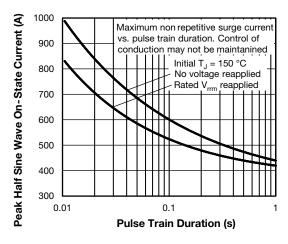


Fig. 6 - Maximum Non-Repetitive Surge Current

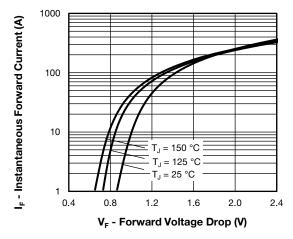


Fig. 7 - On-State Voltage Drop Characteristics

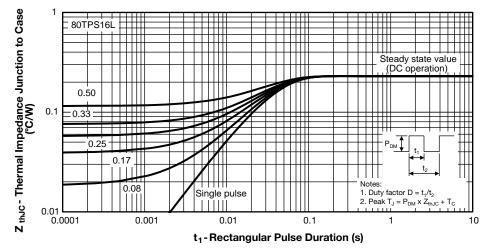
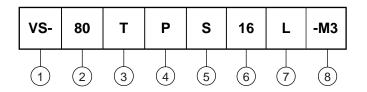


Fig. 8 - Maximum Thermal Impedance ZthJC Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current code (80 = 80 A)

- Circuit configuration:

T = thyristor

4 - P = TO-247 package

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage code (16 = 1600 V)

7 - Package L = long lead

- -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

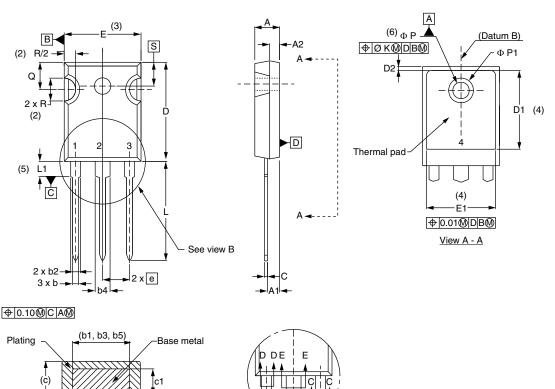
ORDERING INFORMATION (example)					
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-80TPS16L-M3	25	500	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS		
Dimensions <u>www.vishay.com/doc?95626</u>		
Part marking information	www.vishay.com/doc?95007	



TO-247AD 3L

DIMENSIONS in millimeters and inches



		Section C -	C, D - D, E -	<u>· E</u>	
SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	

0.039

0.065

0.065

0.102

0.102

0.015

0.015

0.776

0.515

0.053

0.094

0.092

0.135

0.133

0.035

0.033

0.815

(h h2 h4)

:5	

View B

SYMBOL	MILLIMILILIA		INOTILS		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215 BSC		
ØΚ	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		
•	•		•		•

INCHES

MILLIMETERS

Notes

b1

b2

b3

b4

b5

С

с1

D

D1

(1) Dimensioning and tolerancing per ASME Y14.5M-1994

1.35

2.39

2.34

3.43

3.38

0.89

0.84

20.70

- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

3

- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1

0.99

1.65

1.65

2.59

2.59

0.38

0.38

19.71

13.08

- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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